

Sichao Du

List of Publications by Year in descending order

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Version: 2024-02-01

21
papers

1,069
citations

840776

11
h-index

839539

18
g-index

21
all docs

21
docs citations

21
times ranked

2250
citing authors

#	ARTICLE	IF	CITATIONS
1	Macroscopic assembled graphene nanofilms based room temperature ultrafast mid-infrared photodetectors. <i>InformaAnMateriAjly</i> , 2022, 4, .	17.3	24
2	Bidirectional mid-infrared communications between two identical macroscopic graphene fibres. <i>Nature Communications</i> , 2020, 11, 6368.	12.8	32
3	Broadband optoelectronic synaptic devices based on silicon nanocrystals for neuromorphic computing. <i>Nano Energy</i> , 2018, 52, 422-430.	16.0	150
4	3D Atomic-Scale Insights into Anisotropic Core-Shell-Structured InGaAs Nanowires Grown by Metal-Organic Chemical Vapor Deposition. <i>Advanced Materials</i> , 2017, 29, 1701888.	21.0	15
5	Photodetectors: A Broadband Fluorographene Photodetector (<i>Adv. Mater.</i> 22/2017). <i>Advanced Materials</i> , 2017, 29, .	21.0	1
6	A Broadband Fluorographene Photodetector. <i>Advanced Materials</i> , 2017, 29, 1700463.	21.0	110
7	Plasmonic Silicon Quantum Dots Enabled High-Sensitivity Ultrabroadband Photodetection of Graphene-Based Hybrid Phototransistors. <i>ACS Nano</i> , 2017, 11, 9854-9862.	14.6	285
8	Graphene/silicon-quantum-dots/Si Schottky-PN cascade heterojunction for short-wavelength infrared photodetection. , 2017, , .		11
9	Contacts between Two- and Three-Dimensional Materials: Ohmic, Schottky, and $p-n$ Heterojunctions. <i>ACS Nano</i> , 2016, 10, 4895-4919.	14.6	308
10	Methodology exploration of specimen preparation for atom probe tomography from nanowires. <i>Ultramicroscopy</i> , 2015, 159, 427-431.	1.9	6
11	Atomic-scale observation of parallel development of super elasticity and reversible plasticity in GaAs nanowires. <i>Applied Physics Letters</i> , 2014, 104, .	3.3	26
12	Magnetic properties of fluffy Fe ₃ O ₄ -Fe ₂ O ₃ core-shell nanowires. <i>Nanoscale Research Letters</i> , 2013, 8, 423.	5.7	13
13	Quantitative dopant distributions in GaAs nanowires using atom probe tomography. <i>Ultramicroscopy</i> , 2013, 132, 186-192.	1.9	29
14	Full tip imaging in atom probe tomography. <i>Ultramicroscopy</i> , 2013, 124, 96-101.	1.9	23
15	Spatial decomposition of molecular ions within 3D atom probe reconstructions. <i>Ultramicroscopy</i> , 2013, 132, 92-99.	1.9	5
16	Quantification of the zinc dopant concentration in GaAs nanowires. , 2012, , .		0
17	Single Crystal Kinked ZnO [001] and [110] Nanowires: Synthesis, Characterization, and Growth/Kinking Mechanism. <i>Crystal Growth and Design</i> , 2012, 12, 3153-3157.	3.0	6
18	Investigation of ion implantation induced intermixing in InP based quaternary quantum wells. <i>Journal Physics D: Applied Physics</i> , 2011, 44, 475105.	2.8	6

#	ARTICLE	IF	CITATIONS
19	Investigations of impurity-free vacancy disordering in (Al)InGaAs(P)/InGaAs quantum wells. Semiconductor Science and Technology, 2010, 25, 055014.	2.0	10
20	Comparison of proton and arsenic implantation-induced intermixing in InGaAsP/InGaAs/InP and InAlGaAs/InGaAs/InP quantum wells. , 2008, , .		0
21	Multiple Wavelength InGaAs Quantum Dot Lasers Using Ion Implantation Induced Intermixing. Nanoscale Research Letters, 2007, 2, 550-553.	5.7	9